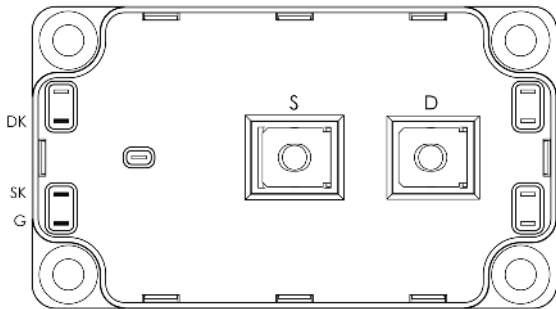
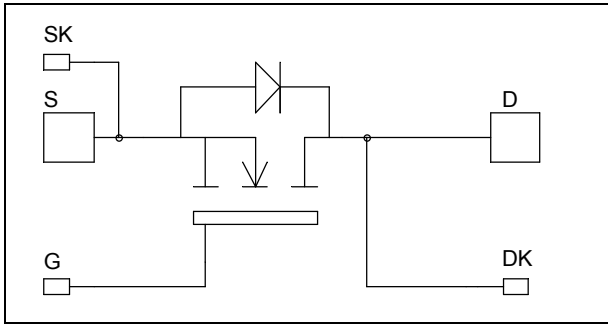


## Single Switch MOSFET Power Module

$V_{DSS} = 100V$   
 $R_{DSon} = 2.25m\Omega \text{ typ @ } T_j = 25^\circ C$   
 $I_D = 570A^* \text{ @ } T_c = 25^\circ C$



### Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

### Features

- Power MOS V<sup>®</sup> FREDFETs
  - Low  $R_{DSon}$
  - Low input and Miller capacitance
  - Low gate charge
  - Avalanche energy rated
  - Fast intrinsic diode
  - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration
- AIN substrate for improved thermal performance

### Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

### Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
$V_{DSS}$	Drain - Source Breakdown Voltage	100	V
$I_D$	Continuous Drain Current	$T_c = 25^\circ C$	570 *
		$T_c = 80^\circ C$	429
$I_{DM}$	Pulsed Drain current	1900	A
$V_{GS}$	Gate - Source Voltage	$\pm 30$	V
$R_{DSon}$	Drain - Source ON Resistance	2.5	$m\Omega$
$P_D$	Maximum Power Dissipation	$T_c = 25^\circ C$	1660
$I_{AR}$	Avalanche current (repetitive and non repetitive)	100	A
$E_{AR}$	Repetitive Avalanche Energy	50	mJ
$E_{AS}$	Single Pulse Avalanche Energy	3000	

\* Specification of MOSFET device but output current must be limited to 500A to not exceed a delta of temperature greater than 100°C for the connectors.

**CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on [www.microsemi.com](http://www.microsemi.com)

All ratings @  $T_j = 25^\circ\text{C}$  unless otherwise specified

**Electrical Characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 100V$			400	$\mu\text{A}$
		$V_{GS} = 0V, V_{DS} = 80V$			2000	
$R_{DS(on)}$	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 200A$		2.25	2.5	$\text{m}\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 10\text{mA}$	2		4	V
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 30V, V_{DS} = 0V$			$\pm 400$	nA

**Dynamic Characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$		40		nF
$C_{oss}$	Output Capacitance	$V_{DS} = 25V$		15.7		
$C_{rss}$	Reverse Transfer Capacitance	$f = 1\text{MHz}$		5.9		
$Q_g$	Total gate Charge	$V_{GS} = 10V$ $V_{Bus} = 50V$ $I_D = 400A$		1360		nC
$Q_{gs}$	Gate – Source Charge			240		
$Q_{gd}$	Gate – Drain Charge			720		
$T_{d(on)}$	Turn-on Delay Time	<b>Inductive switching</b> $V_{GS} = 15V$ $V_{Bus} = 66V$ $I_D = 400A$ $R_G = 1.25\Omega$		160		ns
$T_r$	Rise Time			240		
$T_{d(off)}$	Turn-off Delay Time			500		
$T_f$	Fall Time			160		
$E_{on}$	Turn-on Switching Energy	<b>Inductive switching @ 25°C</b> $V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 400A, R_G = 1.25\Omega$		2.2		mJ
$E_{off}$	Turn-off Switching Energy			2.41		
$E_{on}$	Turn-on Switching Energy	<b>Inductive switching @ 125°C</b> $V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 400A, R_G = 1.25\Omega$		2.43		mJ
$E_{off}$	Turn-off Switching Energy			2.56		

**Source - Drain diode ratings and characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
$I_S$	Continuous Source current (Body diode)	$T_c = 25^\circ\text{C}$			570*	A	
		$T_c = 80^\circ\text{C}$			429		
$V_{SD}$	Diode Forward Voltage	$V_{GS} = 0V, I_S = -400A$			1.3	V	
dv/dt	Peak Diode Recovery ①				5	V/ns	
$t_{rr}$	Reverse Recovery Time	$I_S = -400A$ $V_R = 66V$ $di_S/dt = 400A/\mu\text{s}$	$T_j = 25^\circ\text{C}$			190	ns
			$T_j = 125^\circ\text{C}$			370	
$Q_{rr}$	Reverse Recovery Charge		$T_j = 25^\circ\text{C}$		1.6		$\mu\text{C}$
			$T_j = 125^\circ\text{C}$		6.8		

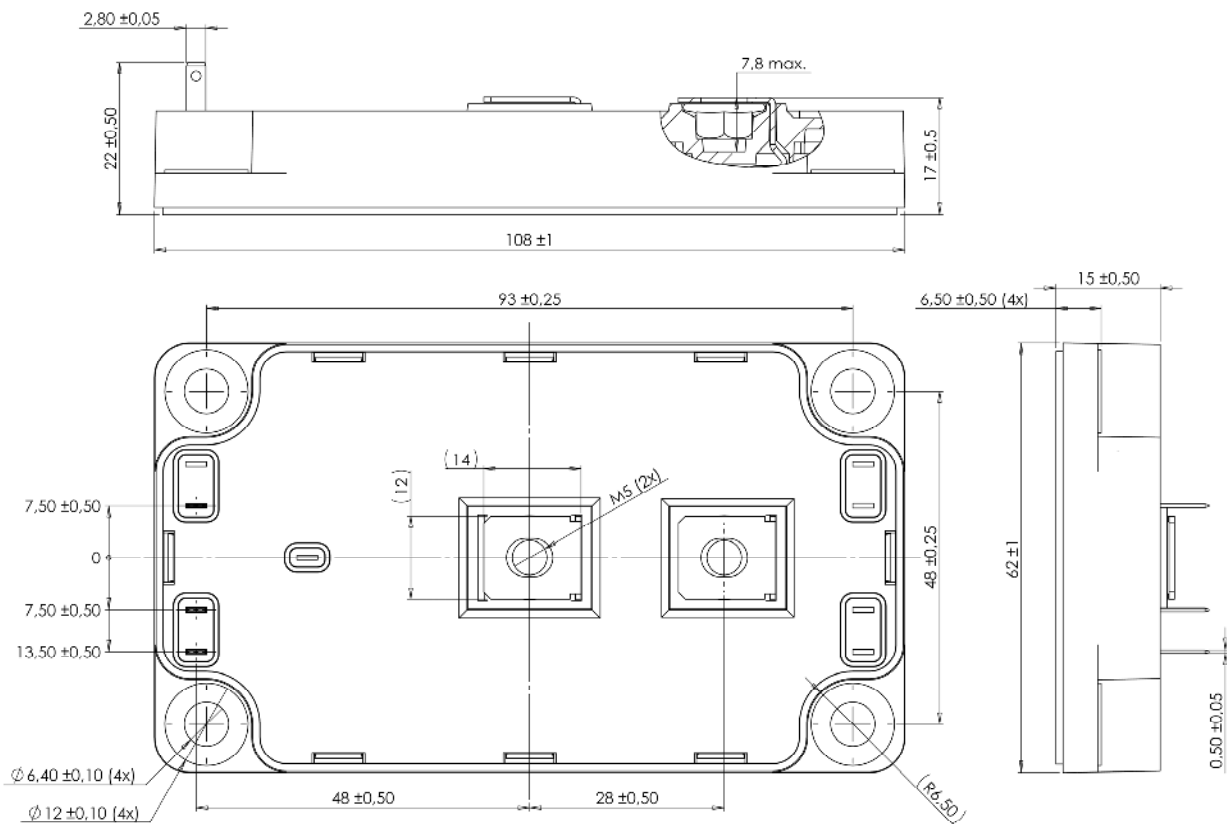
① dv/dt numbers reflect the limitations of the circuit rather than the device itself.

$$I_S \leq -570A \quad di/dt \leq 400A/\mu\text{s} \quad V_R \leq V_{DSS} \quad T_j \leq 150^\circ\text{C}$$

## Thermal and package characteristics

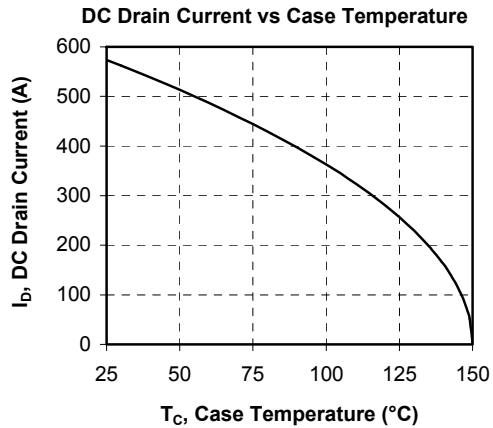
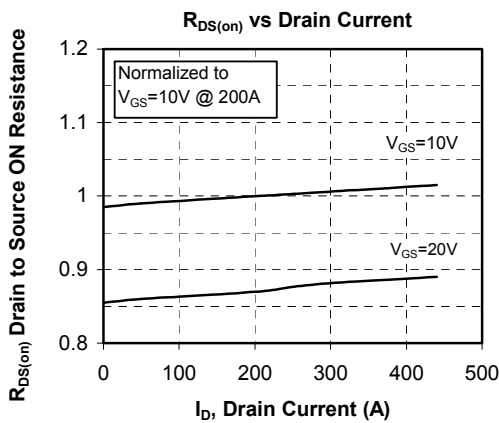
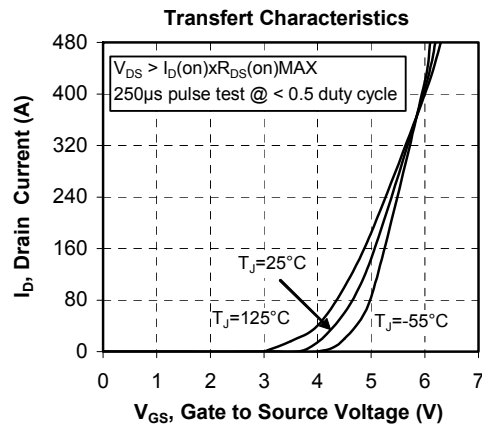
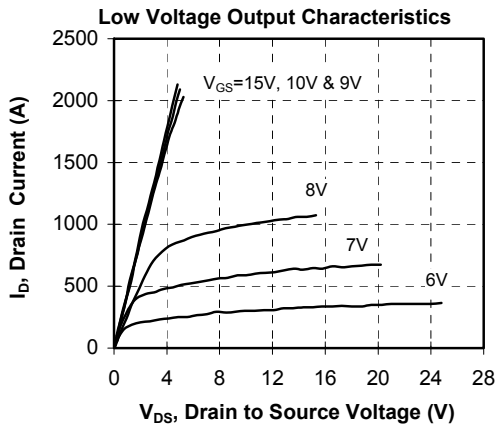
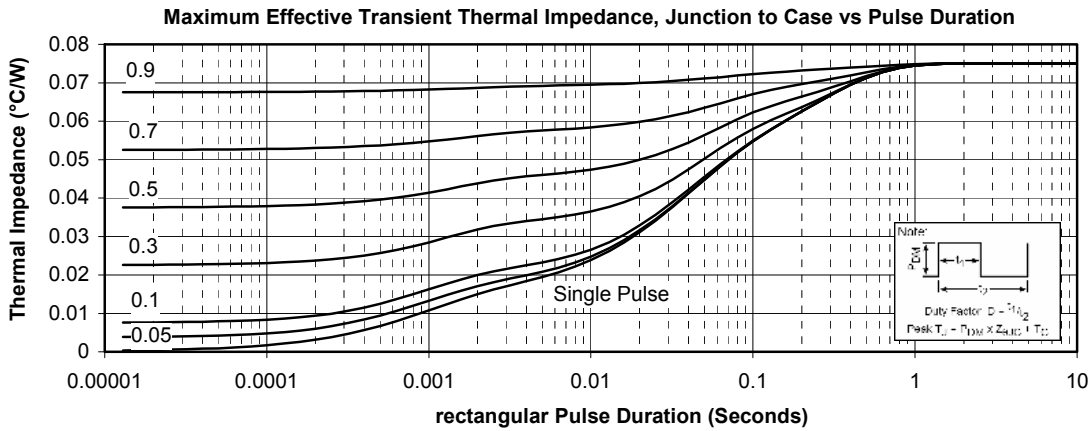
Symbol	Characteristic	Min	Typ	Max	Unit	
R <sub>thJC</sub>	Junction to Case Thermal Resistance			0.075	°C/W	
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t=1 min, 50/60Hz	4000			V	
T <sub>J</sub>	Operating junction temperature range	-40		150	°C	
T <sub>STG</sub>	Storage Temperature Range	-40		125		
T <sub>C</sub>	Operating Case Temperature	-40		100		
Torque	Mounting torque	To heatsink	M6	3	5	N.m
		For terminals	M5	2	3.5	
Wt	Package Weight			300	g	

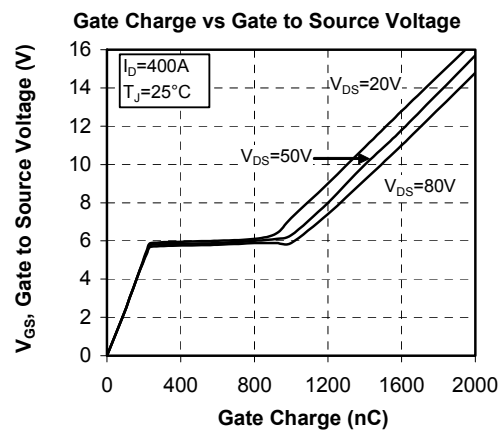
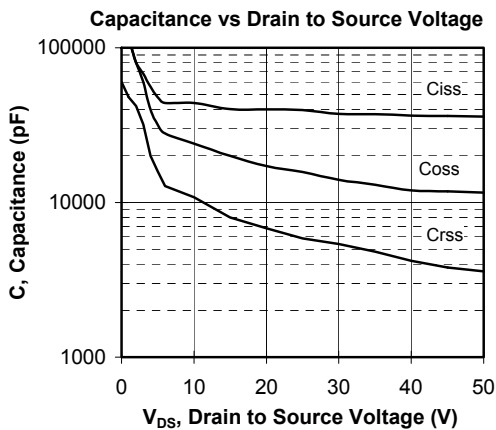
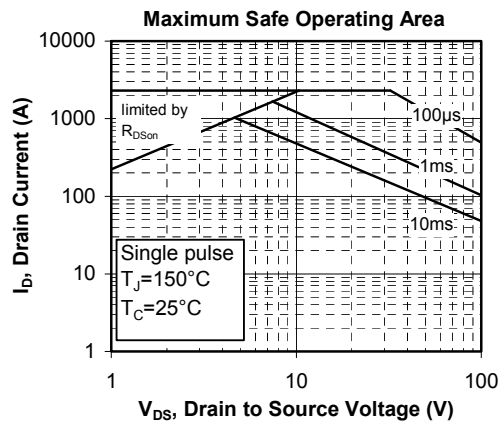
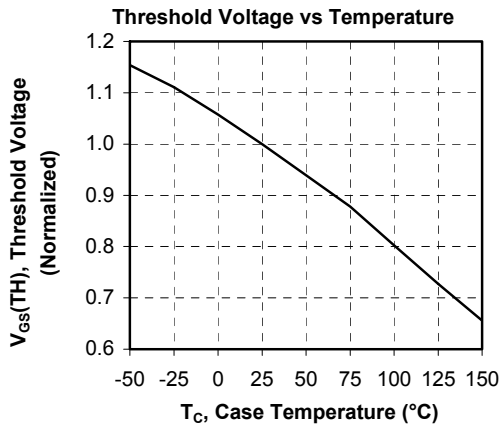
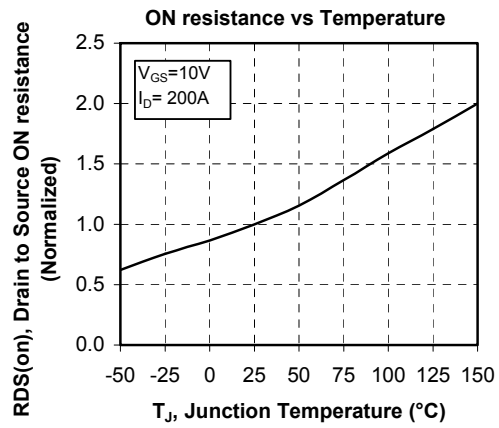
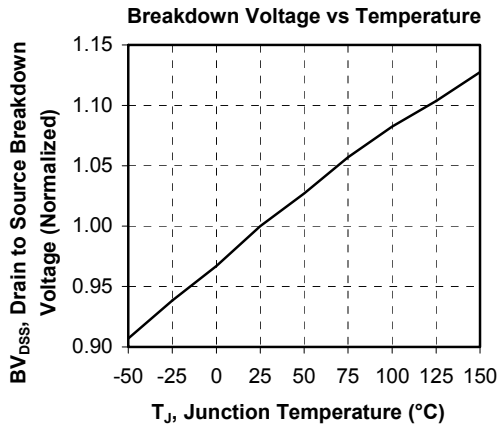
## SP6 Package outline (dimensions in mm)

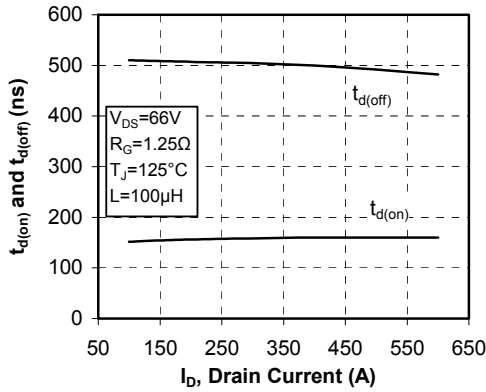
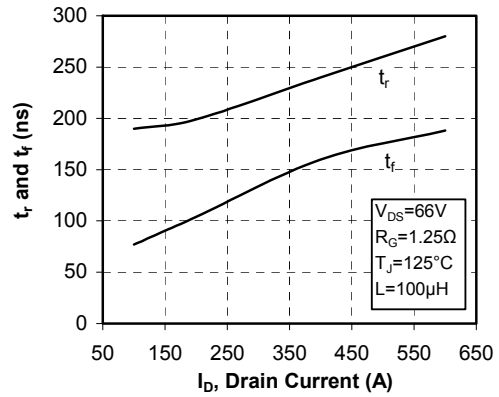
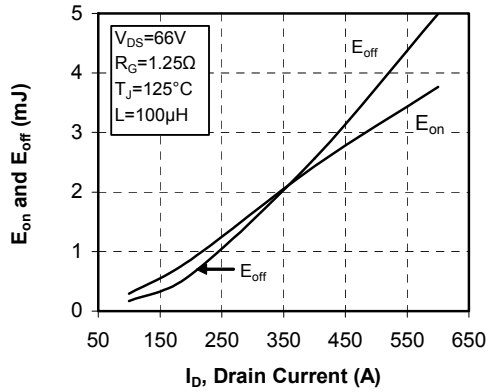
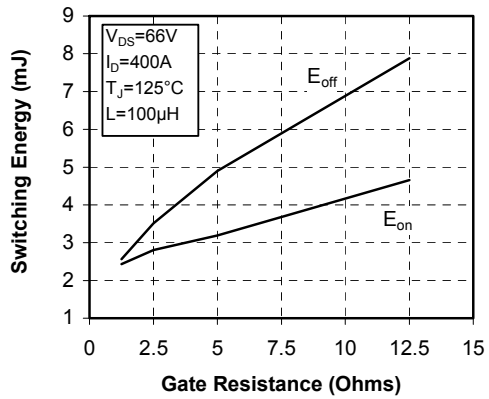
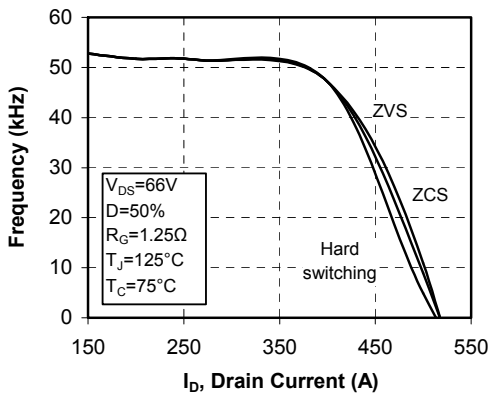
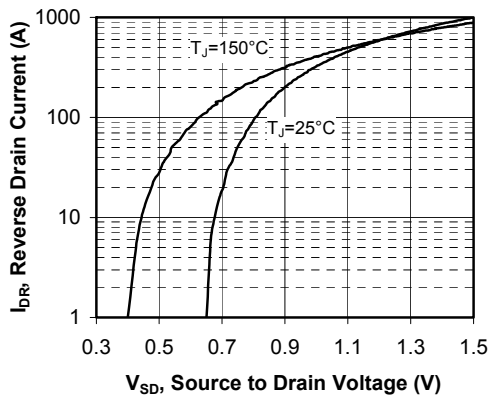


See application note APT0601 - Mounting Instructions for SP6 Power Modules on [www.microsemi.com](http://www.microsemi.com)

## Typical Performance Curve





**Delay Times vs Current**

**Rise and Fall times vs Current**

**Switching Energy vs Current**

**Switching Energy vs Gate Resistance**

**Operating Frequency vs Drain Current**

**Source to Drain Diode Forward Voltage**


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